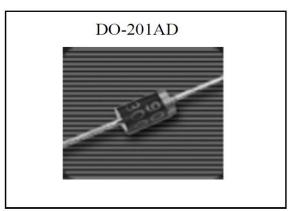


CYStech Electronics Corp.

Spec. No. : K175LD Issued Date : 2015.04.10 Revised Date : 2016.09.26 Page No. : 1/5

5Amp. MOS BARRIER RECTIFIER SKM545ULD

IF(AV)	5A
Vrrm	45V
VF at 125°C	0.42V
Tj	150°C



Features

- 150° C operating junction temperature
- Softest, fast switching capability
- Reduced ultra-low forward voltage drop (VF) ; better efficiency and cooler operation.
- Lead-Free Finish; RoHS Compliant
- Halogen and Antimony Free. "Green" Device
- MCD technology provides a superior avalanche capability than schottky diodes

Mechanical Data

- Case: DO-201AD molded plastic
- Terminals: Plated axial leads, solderable per MIL-STD-750 method
- Polarity: Color band denotes cathode end.
- Epoxy: UL 94V-0 rate flame retardant
- Polarity : As marked.

Maximum Ratings and Electrical Characteristics

(Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.)

Parameter				Min.	Тур.	Max.	Units
Maximum DC blocking voltage			VDC			45	V
Maximum Recurrent peak reverse voltage						45	V
Maximum RMS voltage						32	V
Maximum instantaneous forward voltage Tc=25°C			VF		0.46	0.49	
at IF=15A	Tc=125°C		V F		0.42	0.45	V
Maximum instantaneous	Vr=45 V, Tc=25°C		Ir		60	300	μA
reverse current at	Vr=45 V, Tc=125°C		IR		15	35	mA



CYStech Electronics Corp.

Spec. No. : K175LD Issued Date : 2015.04.10 Revised Date : 2016.09.26 Page No. : 2/5

Maximum Average forward rectified current @ Tc=100°C	IF(AV)		5	Α
Non-repetitive peak forward surge current @				
8.3ms single half sine wave superimposed on	IFSM	120		А
rated load (JEDEC method)				
Peak Repetitive Reverse Surge Current (2uS-1Khz)	Irrm		2	А
Storage temperature range	Tstg	-55	150	°C
Operating junction temperature range	TJ	-55	150	°C

Thermal Data

Parameter	Symbol	Value	Unit
Typical Thermal Resistance, Junction-to-ambient(1)	Rth,j-a	60	°C/W
Typical Resistance, Junction-to-lead(2)	Rth,j-l	10	°C/W

Note

1. 10mm lead length between copper pad

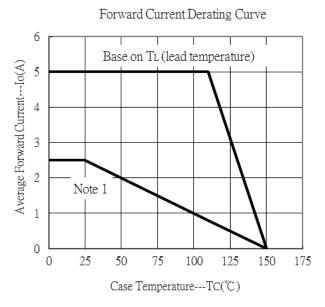
2. Thermal resistance, junction to lead, vertical PCB mounted, 0.375" (9.5mm) lead length

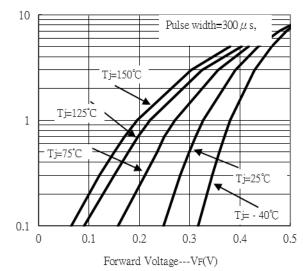


Instantaneous Forward Current---IF(A)

Spec. No. : K175LD Issued Date : 2015.04.10 Revised Date : 2016.09.26 Page No. : 3/5

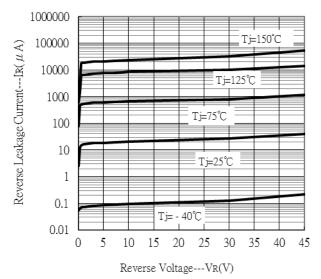
Typical Characteristics



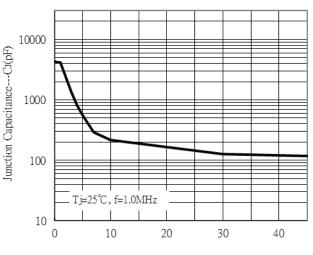


Forward Current vs Forward Voltage

Reverse Leakage Current vs Reverse Voltage



Junction Capacitance vs Reverse Voltage



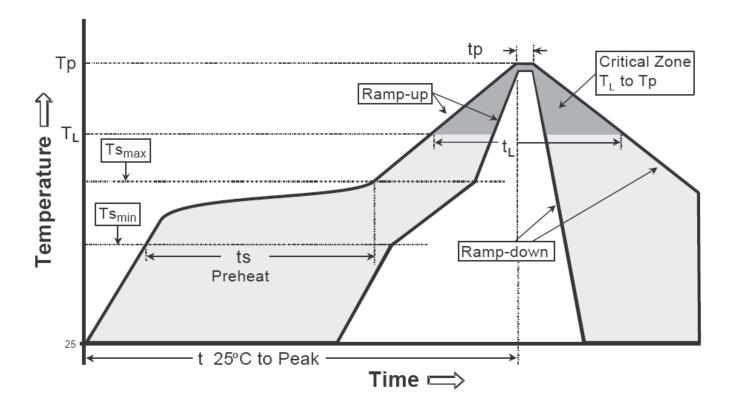
Reverse Voltage---VR(V)



Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat -Temperature Min(Ts min) -Temperature Max(Ts max) -Time(ts min to ts max)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
Time maintained above: -Temperature (TL) - Time (tL)	183°C 60-150 seconds	217°C 60-150 seconds
Peak Temperature(TP) Time within 5°C of actual peak temperature(tp)	240 +0/-5 °C 10-30 seconds	260 +0/-5 °C 20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

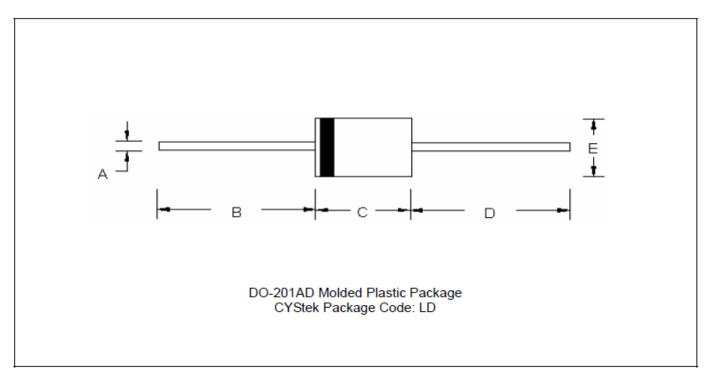
Note : All temperatures refer to topside of the package, measured on the package body surface.



CYStech Electronics Corp.

Spec. No. : K175LD Issued Date : 2015.04.10 Revised Date : 2016.09.26 Page No. : 5/5

DO-201AD Dimension



DIM	Inc	hes	Millim	eters	DIM	Inches		Millimeters	
DIM	Min.	Max.	Min.	Max.	DIM	Min.	Max.	Min.	Max.
Α	φ0.048	φ0.052	φ1.20	φ1.30	D	1.000	-	25.40	-
В	1.000	-	25.40	-	E	φ0.190	φ0.210	φ4.80	φ5.30
С	0.285	0.375	7.20	9.50					

Notes : 1.Controlling dimension : millimeters.

2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material. 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material :

Lead : Axial leads, solderable per MIL-STD-750, Method 2026 guaranteed.

· Mold Compound : Epoxy resin family, flammability solid burning class: UL94V-0

Important Notice:

• All rights are reserved. Reproduction in whole or in part is prohibited without the prior written approval of CYStek.

• CYStek reserves the right to make changes to its products without notice.

- CYStek semiconductor products are not warranted to be suitable for use in Life-Support Applications, or systems.
- CYStek assumes no liability for any consequence of customer product design, infringement of patents, or application assistance.